Calibration Kit User Guide

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SYNOPSYS[®]

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The Calibration Kit is the calibration environment that is part of Synopsys Sentaurus[™] Workbench Advanced. The Calibration Kit is the interface to the calibration libraries and calibration files.

Related Publications

For additional information, see:

- The documentation installed with the Calibration Kit software package and available from the **Help** menu of the Calibration Kit.
- The TCAD Sentaurus release notes, available on the Synopsys SolvNet® support site (see Accessing SolvNet on page vi).
- Documentation available on SolvNet at https://solvnet.synopsys.com/DocsOnWeb.

Conventions

The following conventions are used in Synopsys documentation.

Convention	Description
Blue text	Identifies a cross-reference (only on the screen).
Bold text	Identifies a selectable icon, button, menu, or tab. It also indicates the name of a field or an option.
Courier font	Identifies text that is displayed on the screen or that the user must type. It identifies the names of files, directories, paths, parameters, keywords, and variables.
Italicized text	Used for emphasis, the titles of books and journals, and non-English words. It also identifies components of an equation or a formula, a placeholder, or an identifier.
Menu > Command	Indicates a menu command, for example, File > New (from the File menu, select New).

Customer Support

Customer support is available through the Synopsys SolvNet customer support website and by contacting the Synopsys support center.

Accessing SolvNet

The SolvNet support site includes an electronic knowledge base of technical articles and answers to frequently asked questions about Synopsys tools. The site also gives you access to a wide range of Synopsys online services, which include downloading software, viewing documentation, and entering a call to the Support Center.

To access the SolvNet site:

- 1. Go to the web page at https://solvnet.synopsys.com.
- 2. If prompted, enter your user name and password. (If you do not have a Synopsys user name and password, follow the instructions to register.)

If you need help using the site, click **Help** on the menu bar.

Contacting Synopsys Support

If you have problems, questions, or suggestions, you can contact Synopsys support in the following ways:

- Go to the Synopsys Global Support Centers site on synopsys.com. There you can find email addresses and telephone numbers for Synopsys support centers throughout the world.
- Go to either the Synopsys SolvNet site or the Synopsys Global Support Centers site and open a case online (Synopsys user name and password required).

Contacting Your Local TCAD Support Team Directly

Send an e-mail message to:

- support-tcad-us@synopsys.com from within North America and South America.
- support-tcad-eu@synopsys.com from within Europe.
- support-tcad-ap@synopsys.com from within Asia Pacific (China, Taiwan, Singapore, Malaysia, India, Australia).
- support-tcad-kr@synopsys.com from Korea.
- support-tcad-jp@synopsys.com from Japan.

This chapter presents an overview of the Calibration Kit.

Functionality of the Calibration Kit

The Calibration Kit extends the functionality of Sentaurus Workbench, assisting you to perform efficient 1D calibrations of the Synopsys process simulators Sentaurus Process and Sentaurus Process Kinetic Monte Carlo.

Sentaurus Workbench is the primary graphical front end of TCAD Sentaurus that integrates the simulation tools into one environment (see the *Sentaurus*TM *Workbench User Guide*). The Sentaurus Workbench Advanced mode provides customized viewers and wizards for calibration. The **Calibration** menu of Sentaurus Workbench provides wizards for the manipulation of the simulation flow and report generation (see Chapter 2 on page 9).

In combination with the calibration libraries containing secondary ion mass spectrometry (SIMS) data, the Calibration Kit provides a fast, accurate, and reliable method of evaluating and optimizing process conditions. It allows a predictive analysis of the influence of process equipment parameters on electrical device data. In addition, the Calibration Kit helps you to understand the sensitivity of processes to various control parameters, enabling you to optimize equipment operation quickly.

The Calibration Kit is the calibration environment in Sentaurus Workbench Advanced. It serves as a database browser, and a simulation and project manager.

The software package Optimizer, which is integrated in Sentaurus Workbench Advanced, is used for the automatic analysis and optimization of process and calibration parameters (see the *Optimizer User Guide*).

In addition to the analytic extraction in the process simulators, Sentaurus Device can be integrated for electrical parameter extraction, preceded by Sentaurus Mesh for mesh generation.

For visualization, Inspect and Sentaurus Visual are integrated into the Calibration Kit.

Input Modules

Process descriptions and data, which are calibration libraries such as the Calibration Library, as well as simulator calibration files such as Advanced Calibration are used as input to the Calibration Kit.

Calibration Libraries

The calibration libraries are experiment databases consisting of the following directories:

- processes_*
- experiments
- preferences

You can add your own experimental data to the measurement database or create your own database. In the latter case, it is recommended to keep the same directory structure, with process files, profile files, and preference files in three directories (see Defining the Calibration Library on page 29).

The process recipes can use Ligament SPR syntax or Sentaurus Process syntax, with specific restrictions for the Calibration Kit (see Process File Syntax on page 29). The directory experiments can contain SIMS profiles and spreading resistance profiles.

Process Directory

In the process directory processes_*, each process file contains a recipe for wafer processing and a reference to the corresponding SIMS measurements. By default, these recipes are written in the simple process representation (SPR) syntax of Ligament and do not contain any simulator models or parameters. In this case, the directory is called processes_lig.

The file name of the process is the same as the name of the process. The input files of Sentaurus Process are created automatically before simulation by translating Ligament SPR syntax to Sentaurus Process syntax, and by calibrating the pure recipes with simulation models. For Sentaurus Process, the calibration parameters and models are sourced before a process recipe is applied.

In the process files, the SIMS measurements are represented by insert statements. The insert statement is translated to the Calibration Kit-specific SetPltList statement for Sentaurus Process. In each SetPltList statement, the measured chemical dopant species and the file name of the SIMS profile are specified. A process file can have several SetPltList statements, which correspond to several SIMS profiles.

In a Sentaurus Workbench project generated by the Calibration Kit, the file names of the process flows are changed to b@node@_fps.cmd, where @node@ is the number of a project node of Sentaurus Workbench. For details, see Structure of Calibration Kit Projects on page 5.

Experiment Directory

The experiment directory experiments contains the measured SIMS profiles in xy format. The first column is the depth [nm] and the second column is the concentration of the chemical dopant $[\text{cm}^{-3}]$. The file names match exactly the names specified in the 1D commands of the recipe files.

In a Sentaurus Workbench project generated by the Calibration Kit, the SIMS profiles are named b@node@_[profile].plx, where @node@ is the number of a project node of Sentaurus Workbench. For details, see Structure of Calibration Kit Projects on page 5.

Preference Directory

The preference directory preferences contains additional information. For each SIMS profile name.sims in the experiments directory, there is one preference file name_sims.prf in the preferences directory that specifies the following (Tcl) variables:

- sims_xmin and sims_xmax give the depth [nm] range for which the SIMS profile should be compared to the simulation results.
- vis_xmin and vis_xmax are the preferred minimal depth [nm] and maximal depth [nm], respectively, to be shown in a graphical representation of the profile.
- vis_ymin and vis_ymax are the preferred minimal concentration [cm⁻³] and maximal concentration [cm⁻³], respectively, to be shown in a graphical representation of the profile.
- probe_xmax gives the depth [nm] of the contact for device simulation to calculate the sheet resistance.

In a Sentaurus Workbench project generated by the Calibration Kit, all preference files are named b@node@_[profile].prf, where @node@ is the number of a project node of Sentaurus Workbench. For details, see Structure of Calibration Kit Projects on page 5.

Calibration Files

The directory \$STROOT/tcad/\$STRELEASE/lib/fabpackagelib contains calibration (text) files with physical models and parameters for Sentaurus Process and Sentaurus Process Kinetic Monte Carlo.

Advanced Calibration for Sentaurus Process

Two files in the fabpackagelib directory are used for calibrated 1D simulations of Sentaurus Process with the Calibration Kit: AdvCal_2017.09.fps and calib_1d_2017.09.fps.

The file AdvCal_2017.09.fps is the latest version of Advanced Calibration for Sentaurus Process. It contains a selection of physical models and parameters that are calibrated for deep-submicron technology. This file is identical to the AdvCal_2017.09.fps file in the directory \$STROOT/tcad/\$STRELEASE/lib/sprocess/TclLib/AdvCal.

NOTE When improvements to the model calibration are made, between feature releases, the file in the fabpackagelib directory will contain the latest version. The contents of the AdvCal_2017.09.fps file are explained in the *Advanced Calibration for Process Simulation User Guide*, which can be accessed from Sentaurus Workbench (**Help > Manuals**).

The file calib_1d_2017.09.fps contains information needed for simulations, which does not belong to the process flow or the physical models, and includes:

- The creation of a 1D simulation mesh, which is optimized for accurate 1D simulations.
- A procedure (WritePlt) definition for writing 1D profiles in .plt format.
- A procedure (OxideThickness) definition for extracting the cap-oxide thickness.
- A selection of meshing parameters.

The last lines of the calib_1d_2017.09.fps file create a 1D mesh and source the file AdvCal_2017.09.fps, which contains the physical models.

NOTE Older versions of the calibration files are available in the directory \$STROOT/tcad/\$STRELEASE/lib/fabpackagelib and can be used with the latest release of Sentaurus Process.

Advanced Calibration for Sentaurus Process Kinetic Monte Carlo

Two files in the fabpackagelib directory are used for calibrated pseudo-1D simulations of Sentaurus Process Kinetic Monte Carlo (Sentaurus Process KMC) with the Calibration Kit: AdvCal_KMC_2017.09.fps and calib_KMC_2017.09.fps.

The file AdvCal_KMC_2017.09.fps is the latest version of Advanced Calibration for Sentaurus Process KMC. It contains a selection of physical models and parameters that are calibrated for deep-submicron technology. This file is identical to the AdvCal_KMC_2017.09.fps file in the directory \$STROOT/tcad/\$STRELEASE/lib/sprocess/TclLib/AdvCal.

The file calib_KMC_2017.09.fps contains information needed for simulations, which does not belong to the process flow or the physical models, and includes:

- The creation of a 3D atomistic simulation cell and a 1D projection mesh, which is optimized for accurate pseudo-1D simulations.
- A procedure (WritePlt) definition for writing 1D profiles in .plt format and for logging the thickness of the amorphous layer.
- A selection of recording options for atomistic data.
- A selection of atomistic parameters.

The last lines of the calib_KMC_2017.09.fps file create the simulation cell, select the atomistic mode, and source the file AdvCal_KMC_2017.09.fps, which contains the physical models.

Structure of Calibration Kit Projects

A Calibration Kit project is a special type of Sentaurus Workbench project with either three or five tools, and one to seven parameters. For details about Sentaurus Workbench and its general project structure, see the *SentaurusTM Workbench User Guide*.

Figure 1 shows an example of a Calibration Kit project. The first tool instance in the tool flow is Sentaurus Process for process simulation. Optionally, a Sentaurus Mesh tool instance can be used for mesh generation and a Sentaurus Device tool instance can be used for device simulation. The Inspect tool instance for variable value extraction is followed by Sentaurus Visual for visualization.

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	3	8			Example_Process_As	As 5keV 1e15 7/0	calib_1d.fps
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Figure 1 Calibration Kit project loaded in Sentaurus Workbench; tool flow is horizontal and experiment flow is vertical

The parameter nr of Sentaurus Process represents the index of the process. Each experiment has a unique process recipe. The process file-naming convention is b@nr@_fps.cmd for Sentaurus Process. In general, files starting with b@nr@_* belong to the experiment of the parameter value @nr@.

The Calibration Kit uses different Sentaurus Workbench variables:

- process names the process recipe.
- process_info lists process information.
- n_profile shows the number of profiles per experiment, which are named by the variables profile_@integer@, where integer is equal to 1, 2, 3, ..., 10.

For each profile, the file b@nr@_@{profile_@integer@}@.plx contains the experiment data, and the file b@nr@_@{profile_@integer@}@.prf contains the preferences.

To identify a Sentaurus Workbench project as a Calibration Kit project, an empty hidden file .fabpackage is included in the project directory. The greadme.txt file (**Project** > **Readme**) can be used to collect project information.

Sentaurus Process

The project structure is the same for Sentaurus Process in continuum mode or in kinetic Monte Carlo mode. The mode is defined in the calibration files.

Sentaurus Process uses the command file n@node@_fps.cmd as input. This command file sources the calibration@ of Sentaurus Process, evaluates the parameter nr for each experiment, and sources the process recipe b@nr@_fps.cmd. Therefore, the parameter nr of Sentaurus Process represents the process.

The output of the Sentaurus Process tool instance is the following files:

- b@nr@_@{profile_@integer@}@_simulation.plt (xy plot file)
- b@nr@ fps.tdr (TDR file)
- b@nr@_bnd.tdr (TDR boundary file)

Therefore, the file name of the simulated profile (the xy plot file b@nr@_@{profile_@integer@}@_simulation.plt) differs only from the file name of the measured profile (the b@nr@_@{profile_@integer@}@.plx file) in its file extension.

The Sentaurus Process tool instance defines the variables process, process_info, calibration, n_profile, and profile_@integer@. Sentaurus Process can have a second parameter (see Creating a New Parameterized Project on page 17).

Sentaurus Process is called with the command-line option -n to switch off the syntax check.

Optionally, you can extract the sheet resistance analytically using the Sentaurus Process command SheetResistance, and the result is transferred to the Sentaurus Workbench variable Rs_fps.

For Sentaurus Process KMC, you can store the atomistic information using the following command:

kmc extract tdrWrite

Sentaurus Mesh (Optional)

Sentaurus Mesh is used for the mesh generation of a 2D device simulation. For the calculation of sheet resistance, a 2D device is defined to represent the sheet of an ultrashallow junction of a transistor. The device definition is taken from the output files b@nr@_fps.tdr and b@nr@_bnd.tdr of Sentaurus Process.

The geometry is described by the following variables defined for Sentaurus Mesh:

- x_sheet defines the length $[\mu m]$ of the sheet (default is 20 μm).
- y_sheet defines the depth [µm] of the sheet.
- y0 sheet defines the top position [μm] of the sheet.
- y_contact defines the depth [μm] of the contacts.
- y0_contact defines the top position [μm] of the contacts.

The doping and grid information is stored in the n@node@_msh.tdr file.

Sentaurus Device (Optional)

Sentaurus Device performs a 2D device simulation on the sheet defined in the n@node|mesh@_msh.tdr file. The voltage and the total current distribution of the sheet are computed for a voltage of 0.01 V between the left and right contacts. The results are saved in the n@node@_des.plt file. Sentaurus Device uses the default parameters for silicon, germanium, and SiGe from files by specifying the DefaultParametersFromFile flag in the global Physics section of the command file. The optional parameter file of Sentaurus Device is named sdevice.par.

Inspect

Inspect calculates the sheet resistance and the curve differences. From the file n@node|sdevice@_des.plt, Inspect takes the voltage and the total current distribution, and calculates the sheet resistance. The results are stored in the Sentaurus Workbench variable Rs_sim. You can compare the extracted value with the experimental data for some experiments. The variable Rs_exp, which is defined by Sentaurus Process, retains the measured value or is set to zero if no measurement value is present.

For each profile pair, Inspect computes the difference between the measured profile and the simulated profile, that is, between b@nr@_@{profile_@integer@}@.plx and b@nr@_@{profile_@integer@}@_simulation.plt.

Different methodologies are available for this curve comparison (see Comparing Profile Curves on page 35). The variables $cv_delta_@integer@$, where integer is equal to 1, 2, 3, ..., 10, hold the extracted curve difference per μm for profile_@integer@.

You can view the profiles in interactive mode. If you want to save the visualization in the Inspect format, this must be performed manually.

Optionally, a spline-based curve-smoothing (a smooth, piecewise, polynomial approximation) is applied to the measured profile or the simulated profile for curve comparison.

See Viewing Profile Files on page 27.

Sentaurus Visual

Sentaurus Visual visualizes all measured and simulated profiles of a process in one xy plot. For each node, Sentaurus Visual takes all profiles (b@nr@_@{profile_@integer@}@.plx and b@nr@_@{profile_@integer@}@_simulation.plt), the curve comparison results (cv_delta_@integer@), and the preferences (b@nr@_@{profile_@integer@}@.prf), and creates a Sentaurus Visual Tcl script n@node@_vis_out.tcl for customized xy plot visualization.

All profiles of the experiment are plotted on top of each other. The curve comparison results cv_delta_@integer@ are listed next to the curve label of the corresponding simulated profile. The borders of the curve comparison of the last profile pair are drawn in dashed style.

See Viewing Visualization Files on page 27.

CHAPTER 2 Working With Calibration Kit Projects

This chapter describes how to work with Calibration Kit projects.

Manipulating Calibration Kit Projects

A Calibration Kit project can be manipulated like other Sentaurus Workbench projects (for details about editing projects, see the *Sentaurus*[™] *Workbench User Guide*). However, you can use special wizards of the Calibration Kit to guide you through project creation and extension, scenario and experiment generation, and parameterization.

It is faster and more thorough to manipulate projects using these wizards rather than the standard features of Sentaurus Workbench. The wizards are available from the **Calibration** menu of Sentaurus Workbench.

NOTE The **Calibration** menu is shown only in Sentaurus Workbench Advanced mode.

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	<u>Optimization</u>		

Figure 2 Wizards available from Calibration menu

NOTE Renumbering nodes of a Calibration Kit project can lead to a reduction of functionality. It is strongly advised *not* to renumber nodes.

Creating a New Project or a New Scenario for an Existing Project

You can create a new Calibration Kit project or extend an existing project by a new scenario.

To create a new Calibration Kit project or a new scenario to an existing project:

1. Choose Calibration > Project Wizard.

The Project Wizard opens.

- 2. Click Next to start.
- 3. Select the calibration library database from either:
 - **Calibration Library**, which is the experiment database of the Calibration Library in Ligament SPR syntax.
 - User Library, which is a user-specified database in either Ligament SPR syntax or Sentaurus Process syntax.

If you select this option, you must specify the process directory, the experiment directory, and the preference directory, and select the syntax from either Ligament, Sentaurus Process, or TSUPREM-4.

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Click Next to cont	linue.		
Click Next to cont	inue.		

4. Click Next.

- 5. Select a process list in one of the following ways:
 - Under DBPS Database Process Search, type a search pattern in the **Process Search Pattern** field to look for processes using the DBPS in the selected database and syntax (Step 3).

Select the alphabetic order of the process list file from either **Process Names** or **Process Recipes**.

Click the **Search** button to write the results to the selected process list file (see Database Process Search on page 32).

• Click the **Browse** button to select a list or search for a list using the DBPS. (For the syntax of a process list file file.qps, see Process Searches on page 31.)

Click the Edit button to edit the selected list using the SEdit text editor.

- 6. Click Next.
- 7. Select the process simulator and calibration from either:
 - Sentaurus Process (default)

If you choose this option, under Calibration, select the implantation model, and select the diffusion model.

Select either the parameters of **Advanced Calibration** or **User Calibration**, in which case, select up to two calibration files in the Alagator (Tcl) syntax of Sentaurus Process, which usually follow the naming scheme *.fps.

• TSUPREM-4

If you choose this option, under Calibration, select the implantation model.

Select either the parameters of **Advanced Calibration** or **User Calibration**, in which case, select the calibration files.

- 8. Click Next.
- 9. Select the device simulation to calculate the sheet resistance from one of the following options:
 - Device Simulation Disabled (default)
 - Device Simulation Enabled

If this option is selected, the Sentaurus Mesh and Sentaurus Device tool instances are part of the project. Click the **Browse** button to select the parameter file for Sentaurus Device. The file format usually follows the naming convention *.par and is named sdevice.par in the project. If no file is selected, Sentaurus Device uses the default parameters.

10. Click Next.

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Manipulating Calibration Kit Projects

11. Select the methodology for the simulation and the experiment profile comparison from the following options:

For numeric comparison, select one of the following options:

- Relative Logarithmic Square Difference (default)
- Relative Linear Square Difference
- Arithmetic Mean of Relative Error
- Quadratic Mean of Relative Error

The options of the **Noise Filter** field are deactivated by default. Select the options as required to activate the noise filter (spline-based curve-smoothing) for experiment data, or simulation data, or both.

Select the visualization tool. Sentaurus Visual is the default.

- 12. Click Next.
- 13. Select a project and scenario name from the following options:
 - Select the Create New Project option for a new project.

Type the scenario name, and click the **Browse** button to select a project directory or type the project name.

• Select the Add to Project option to add a new scenario to an existing project.

Type the scenario name, and click the Browse button to select a project.

The new experiments will have the same structure as the rest of the project, that is, the selection of device simulation follows the existing project selection.

14. Click Finish.

15. If the project or scenario is created and loaded successfully, click **OK** in the Progress dialog box.

The generated project has the structure of the Calibration Kit described in Structure of Calibration Kit Projects on page 5. For each process in the process list, the Project Wizard creates an experiment that follows the file-naming convention of the Calibration Kit. In the case of a database in Ligament SPR syntax, the process is translated to the syntax of the selected process simulator (see Process File Syntax on page 29). In the case of a database in Sentaurus Process syntax, the process is copied; it is not translated. For Sentaurus Process, the resulting process file is b@nr@_fps.cmd.

The file name of the process sets the variable process. The file names of the profiles set the variables profile_@integer@.

The variable process_info takes INFO as a value if processinfo appears as a remark or comment in the process file. For Ligament, this is:

remark (text : "processinfo 'BF2 2.5keV le15'");

For Sentaurus Process, processinfo is:

processinfo "INFO"

Analogously, the variable Rs_exp is set to VALUE if sheetresistance appears as a remark or comment in the process file. For Ligament, this is:

remark (text : "sheetresistance 'VALUE'")

or:

remark (text : "sheetresistance 'Rs=VALUE'")

For Sentaurus Process, sheetresistance is:

sheetresistance "VALUE"

or:

```
## sheetresistance "Rs=VALUE"
```

The variable y_sheet is set to 1.25 times the valid depth (set as sims_xmax in the preference file) of the deepest profile. If no preference (sims_xmax) is present, the default value of 50 nm is used. In addition, the variable y_contact is set to 0.25 times the valid depth (set as sims_xmax in the preference file) of the shallowest profile, unless the depth is defined explicitly (as probe_xmax in the preference file). If no preference (probe_xmax or sims_xmax) is present, the default value of 5 nm is used.

Defining a New Scenario for a Project

To focus on a specific selection of experiments for a Calibration Kit project, a project can be split into scenarios. For example, a project can be split into scenarios of different dopant elements.

To create a new scenario for a Calibration Kit project:

- 1. Open a Calibration Kit project.
- 2. Choose Calibration > Scenario Wizard.

The Scenario Wizard opens.

3. Click Next to start.

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Manipulating Calibration Kit Projects

4. Under CPPS - Calibration Project Process Search, type a search pattern in the **Process Search Pattern** field to select experiments, and click **Search** (see Calibration Project Process Search on page 33).

\star Calibration Kit Scenario Wi	zard				— — X
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Process Selection			С	alibration K	it Scenario
Select experiments by CPPS.					
CPPS - Calibration Project P	rocess Search-				
Process Search Pattern:					
impl(element==boron)				Search	Help
Click Next to continue					
	< Back	Next >	Finish		Cancel

- 5. Click Next.
- 6. Type the name of the new scenario in the Scenario Name field.
- 7. Click Finish.
- 8. If the scenario is created and loaded successfully, click OK in the Progress dialog box.

The structure of the Calibration Kit project is unchanged by the creation of a new scenario.

Creating a New Short Loop Experiment

You can add a new short loop experiment (in Ligament SPR syntax or Sentaurus Process syntax) to a database or add a new experiment to a Calibration Kit project.

To create a new short loop experiment for a Calibration Kit project:

- 1. Open a Calibration Kit project.
- 2. Choose Calibration > Process Wizard.

The Process Wizard opens.

- 3. Click Next to start.
- 4. Select the substrate and oxide properties.

If the oxide thickness is 0, the oxide deposition step is omitted.

- 5. Click Next.
- 6. Select the implantation properties of the first and second implantations.

If the **Element** field is set to 0, the corresponding implantation step is omitted.

- 7. Click Next.
- 8. Select the anneal ramp properties.

If the **Rate** or **Time** fields are set to 0, the corresponding diffusion step is omitted.

Calibration Kit Process Wiza	ird	
F SPA		
Anneal Ramp		Calibration Kit Process
Select temperatures, rates, times,	, ambient, and partial pre	essure.
3 Temp: Rate:	1000 C Time:	1] sTemp: 1000 C
2		Rate: -50 C/s
1 Temp: 500 C		5 Temp: 500 C
Ambient	n2 ▼ Partial Press	sure: 0
Click Next to continue.		
	< Back Nex	t > Finish Cancel

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Manipulating Calibration Kit Projects

- 9. Click Next.
- 10. Select the properties for the first and second measurements:
 - If the **Element** field is set to 0, the corresponding measurement step is omitted.
 - For the **Experiment Data** field, click **Browse** to select the experimental measurement data (SIMS).

Click View to view the selected SIMS using Inspect.

- Select the depth scale of the selected SIMS.
- For the **Preferences** field, click **Browse** to select the preferences.

Click **Create** to create new preferences and to edit them with the SEdit text editor.

- 11. Click Next.
- 12. Select a process name and syntax:
 - Type the name of a process in the **Name** field.
 - From the **Syntax** field, select the required option.
 - Click the **Edit** button to edit the flow if required.

If Ligament SPR syntax is selected, the flow is loaded into the Ligament Flow Editor. If Sentaurus Process syntax is selected, the flow is loaded into a text editor.

If needed, the flow can be further modified beyond the guidelines of the previous wizard pages.

When **Edit** is clicked, the current values of the process steps defined in the previous steps are considered. Further changes to the process through the previous wizard pages no longer affect the flow, unless **Edit** is clicked again.

If **Edit** is clicked again, the current values of the process steps defined in the previous wizard steps are reconsidered, and the previous changes of the flow in the editor are deleted.

13. Click Next.

14. Select whether the process is added to a database or the currently loaded project:

• Select the **Add to Project** option to add a new experiment with the created process flow to the currently loaded Calibration Kit project.

This option is available only if the currently loaded project is a Calibration Kit project and contains the same simulator that was previously selected as the process syntax.

• Select the **Add to User Library** option to add the process flow permanently to a database. Select the process directory for the process recipes, the experiment directory for the measurement data, and the preference directory for the preferences.

15. Click Finish.

16. If the experiment is created successfully, click **OK** in the Progress dialog box.

If added to a database, the process recipe is stored in the same format as those in the calibration libraries (see Process File Syntax on page 29). The process flow includes the correlated profile and process info information.

If added to a project, the experiment has the same structure as the other experiments of the project. The variable process is defined by the process name. If an experiment profile is referenced, the variable profile_@integer@ is defined by the name of the experiment profile. If no experiment profile is referenced, the variable profile_@integer@ is defined by @process-name@_@integer@. Depending on the declared implantation and diffusion steps, the variable process_info is set.

The variable $y_$ sheet is set to 1.25 times the valid depth (set as sims_xmax in the preference file) of the deepest profile. If no preference (sims_xmax) is present, the default value of 50 nm is used. In addition, the variable $y_$ contact is set to 0.25 times the valid depth (set as sims_xmax in the preference file) of the shallowest profile, unless the depth is defined explicitly (as probe_xmax in the preference file). If no preference (probe_xmax or sims xmax) is present, the default value of 5 nm is used.

NOTE If the process flow is edited further after the wizard generation, you must ensure that the variable values (such as the number of profiles n profile) are correct.

Creating a New Parameterized Project

You can create a new Calibration Kit project with new physical Sentaurus Process parameters, and an optional command file for the Optimizer tool.

To create a new Calibration Kit project with new physical Sentaurus Process parameters:

- 1. Open a Calibration Kit project and select an experiment.
- 2. Choose Calibration > Parameter Wizard.

The Parameter Wizard opens.

- 3. Click **Next** to start.
- 4. Parameterize the selected process (the name and simulator syntax of the selected process is displayed):
 - a) Select up to six parameter names for parameter (for example, energy).

b) Select to either Include or Exclude the experiment data.

If experiment data is included, the experiments of the resulting project contain the experiment profiles (SIMS) of the selected experiment.

c) Click Edit to load the flow is loaded into an editor.

Edit the flow by replacing the argument values to be parameterized with @parameter@. For example, for the parameter energy and Sentaurus Process syntax, type:

implant Arsenic dose=1e+15 energy=@energy@ tilt=0 rot=0

Save the file.

- 5. Click Next.
- 6. Specify the parameter values of each parameter on the respective tabs:

🗙 Calibration Kit Parameter Wizard	- T ×
Parameter Values	Calibration Kit Parameter
Select parameter values.	
Parameters	
Parameter 1 Parameter 2 Parameter 3 Parameter 4 Param	ieter 5 Parameter 6
Parameter: tox Min Value: 0.001 Step: 0.003 Number of Values: 1	
◆ Linear 💸 Logarithmic	
Click Next to continue.	
< Back Next >	Finish Cancel

- a) Select the minimal value of the parameter.
- b) Select the iteration step between parameter values.
- c) Select the number of parameter values.

- d) If the **Linear** option is selected, the difference between the values is equal to the iteration step. If the **Log** option is selected, the value of each step is equal to the value of the previous step multiplied by the value of the iteration step.
- 7. Click Next.
- 8. Select a calibration parameter file for the process simulator of the parameterized process file:
 - Under Calibration, select the implantation model, and select the diffusion model.
 - Select either the parameters of **Advanced Calibration** or **User Calibration**, in which case, select up to two calibration files in the Alagator (Tcl) syntax of Sentaurus Process, which usually follow the naming scheme *.fps.
- 9. Click Next.
- 10. Select the device simulation to calculate the sheet resistance from one of the following options:
 - Device Simulation Disabled (default)
 - Device Simulation Enabled

If this option is selected, the Sentaurus Mesh and Sentaurus Device tool instances are part of the project. Click the **Browse** button to select the parameter file for Sentaurus Device. The file format usually follows the naming convention *.par and is named sdevice.par in the project. If no file is selected, Sentaurus Device uses the default parameters.

- 11. Click Next.
- 12. Select an Optimizer task and the corresponding task conditions, if required, from the following options:
 - None
 - Sentaurus PCM Studio
 - Screening
 - Optimization
 - Iterative Optimization
 - Generic Optimization
- 13. Click Next.
- 14. Select the methodology for the simulation and the experiment profile comparison from the following options.

For numeric comparison, select one of the following options:

- Relative Logarithmic Square Difference (default)
- Relative Linear Square Difference
- Arithmetic Mean of Relative Error
- Quadratic Mean of Relative Error

The options of the **Noise Filter** field are deactivated by default. Select the options as required to activate the noise filter (spline-based curve-smoothing) for experiment data, or simulation data, or both.

Select the visualization tool. Sentaurus Visual is the default.

- 15. Click Next.
- 16. Select a project and scenario name:
 - a) Type a scenario name.
 - b) Click **Browse** to select a project directory, or type the project name.
- 17. Click Finish.

18. If the project is created and loaded successfully, click **OK** in the Progress dialog box.

If no Optimizer task is selected (**Task Type** is set to **None**), the new project has the structure of a Calibration Kit project with two to seven parameters, that is, the parameter nr and the selected parameters. The variable process is the selected process name combined with the parameter value. The variable process_info contains the parameter name and value. The values of the variables profile_@integer@ consist of the process name process and sequential numbering, for example, cprocess_1

The project contains as many experiments as there are possible combinations of parameter values.

If an Optimizer task is selected, the new project has the structure of a Calibration Kit project with two to seven parameters, that is, the parameter nr is a user-defined Optimizer parameter and the selected parameters are design-of-experiments (DoE) Optimizer parameters.

The only available variables are the process name process, the calibration file calibration, and the number of profiles per process n_profile. The project contains only one experiment with the mean parameter values. For each pair of profiles, a unique curve comparison variable cv_delta_@integer@_@integer@ is evaluated and is used as a response for the Optimizer tool. The corresponding command file of Optimizer is included in the project.

For information about the Optimizer tool, see the Optimizer User Guide.

Creating a New Project for Optimization

You can create a new Calibration Kit project with new calibration parameters of Sentaurus Process, and an optional command file of the Optimizer tool.

To create a new Calibration Kit project with new calibration parameters of Sentaurus Process:

1. Choose Calibration > Optimization Wizard.

The Optimization Wizard opens.

- 2. Click **Next** to start.
- 3. Select the calibration library database from either:
 - **Calibration Library**, which is the experiment database of the Calibration Library in Ligament SPR syntax.
 - User Library, which is a user-specified database in either Ligament SPR syntax or Sentaurus Process syntax.

If you select this option, you must specify the process directory, the experiment directory, and the preference directory, and select the syntax from either Ligament, **Sentaurus Process**, or **TSUPREM-4**.

- 4. Click Next.
- 5. Select a process list in one of the following ways:
 - Under DBPS Database Process Search, type a search pattern in the **Process Search Pattern** field to look for processes using the DBPS in the selected database and syntax (Step 3).

Select the alphabetic order of the process list file from either **Process Names** or **Process Recipes**.

Click the **Search** button to write the results to the selected process list file (see Database Process Search on page 32).

• Click the **Browse** button to select a list or search for a list using the DBPS. (For the syntax of a process list file file.qps, see Process Searches on page 31.)

Click the **Edit** button to edit the selected list using the SEdit text editor.

- 6. Click Next.
- 7. Select the process simulator and calibration from either:
 - Sentaurus Process (default)

If you choose this option, under Calibration, select the implantation model, and select the diffusion model.

Select either the parameters of **Advanced Calibration** or **User Calibration**, in which case, select up to two calibration files in the Alagator (Tcl) syntax of Sentaurus Process, which usually follow the naming scheme *.fps.

• TSUPREM-4

If you choose this option, under Calibration, select the implantation model.

Select either the parameters of Advanced Calibration or User Calibration, in which case, select the calibration files.

- 8. Click Next.
- 9. Parameterize the selected calibration file by entering the values of the fields for the parameters:
 - **NOTE** For Sentaurus Process, only the second selected calibration file can be parameterized.
 - a) Select up to four parameter names for parameter (for example, ifactor).
 - b) Select the minimal value and the maximal value of a parameter.
 - c) Select either the **Linear** option or the **Logarithmic** option.
 - d) Click **Edit** to load the calibration file into an editor.

Edit the file by replacing the calibration parameter values to be parameterized with Sentaurus Workbench parameter calls @parameter@. (This calibration file will be preprocessed by Sentaurus Workbench as well.)

Save the file.

- 10. Click Next.
- 11. Select an Optimizer task and the corresponding task conditions, if required, from the following options:
 - None

If this option is selected, no Optimizer task is used, but you must select the number of different parameter values for each parameter.

• Sentaurus PCM Studio

If this option is selected, no Optimizer task is used, but you can add more parameter values after the creation of the project.

- Screening
- Optimization

• Iterative Optimization

• Generic Optimization

In addition, the project has a convenient structure for exporting the project view and profiles to Sentaurus PCM Studio. For all other task types, a project with the corresponding Optimizer command file is generated. (For information about Optimizer tasks, see the *Optimizer User Guide*.)

🗸 Calibration Kit Optimization Wizard				
Løø				
Optimizer Command	Calibration Kit Optimization			
Select Sentaurus Workbench	Optimizer task and conditions.			
Optimizer Task Task Type:	Iterative Optimization			
Simulations:	80			
Conditions				
RSM Degree:	2 🗸			
Time:	5 hrs			
Evaluations:	2000			
Interations:	20			
LocalOpt r2Adi:	0.99			
LocalOpt Range:	20			
Click Next to continue.				
	< Back Next > Finish Cancel			

- 12. Click Next.
- 13. Select the device simulation to calculate the sheet resistance from one of the following options:
 - Device Simulation Disabled (default)
 - Device Simulation Enabled

If this option is selected, the Sentaurus Mesh and Sentaurus Device tool instances are part of the project. Click the **Browse** button to select the parameter file for Sentaurus Device. The file format usually follows the naming convention *.par and is named sdevice.par in the project. If no file is selected, Sentaurus Device uses the default parameters.

- 14. Click Next.
- 15. Select the methodology for the simulation and the experiment profile comparison from the following options:

For numeric comparison, select one of the following options:

- Relative Logarithmic Square Difference (default)
- Relative Linear Square Difference
- Arithmetic Mean of Relative Error
- Quadratic Mean of Relative Error

The options of the **Noise Filter** field are deactivated by default. Select the options as required to activate the noise filter (spline-based curve-smoothing) for experiment data, or simulation data, or both.

Select the visualization tool. Sentaurus Visual is the default.

- 16. Click Next.
- 17. Select a project and scenario name:
 - a) Type a scenario name.
 - b) Click **Browse** to select a project directory, or type the project name.
- 18. Click Finish.
- 19. If the project is created and loaded successfully, click **OK** in the Progress dialog box.

If no Optimizer task is selected (**Task Type** is set to **None**), the new project has the structure of a Calibration Kit project with two to seven parameters, that is, the parameter nr and the selected parameters. For each process in the process list and each parameter value combination, the Optimization Wizard creates an experiment that follows the file-naming convention of the Calibration Kit.

In the case of a database in Ligament SPR syntax, the process is translated to the selected process simulator syntax (see Process File Syntax on page 29). In the case of a database in Sentaurus Process syntax, the process is copied; it is not translated. For Sentaurus Process, the resulting process file is b@nr@_fps.cmd.

If an Optimizer task is selected, the new project has the structure of a Calibration Kit project with two to seven parameters, that is, the parameter nr is a user-defined Optimizer parameter and the selected parameters are DoE Optimizer parameters.

The only available variables are the process name process, the calibration file calibration, and the number of profiles per process n_profile. The project contains only one experiment per process in the process list with mean parameter values. For each pair of

profiles, a unique curve comparison variable cv_delta_@integer@_@integer@ is evaluated and is used as a response for Optimizer. The corresponding command file of Optimizer is included in the project.

For information about the Optimizer tool, see the Optimizer User Guide.

Editing Variables

You can change the variable values of a Calibration Kit experiment using Sentaurus Workbench.

To edit a variable:

- 1. Select the corresponding node:
 - This is the second Sentaurus Process node for the variables process, calibration, process_info, Rs_exp, n_profile, and profile_@integer@ (where integer is equal to 1, 2, 3, ..., 10).
 - This is the Sentaurus Mesh node for the variables *_contact and *_sheet.
- 2. Edit the variable values in one of the following ways:
 - Choose Nodes > Set Variable Value.

The Add Variable to Node dialog box is displayed.

Enter the name and the value of the variable, and click **OK**.

• Choose Nodes > Edit Properties.

The Node information dialog box is displayed.

Under Defined Variables, edit the definition of the variable (as shown in the following example), and click **OK**.

Defined Variables		
🔲 process:	Example_Process_As	
🔲 calibration:	calib_1d.fps	
process_info:	As 5keV 1e15 7/0	
profile_1:	example_profile_as_sims	
🔲 n_profile:	1	

Visualizing Project Files

Each Calibration Kit project has dedicated viewers that are defined in the project tool database (gtooldb.tcl) of Sentaurus Workbench. These viewers are specifically for the files of Calibration Kit projects.

Ca <u>l</u> ibration	PCM St <u>u</u> dio	Extensions	<u>H</u> elp		
	🛓 🖉 🛛	1 🦻 🤣		€	×
<u>S</u> enta	aurus Visual (S	elect File)			
Sent <u>a</u>	urus Visual (S	elect by Typ	e)		⊳
Senta	urus <u>V</u> isual (A	ull Files)			
Tech	ot SV (Select	File)			
РЕСТ Теср	ot SV (All File	s)			
Inspe	ct (Select File.)			
I <u>n</u> spe	tt (All Files)				
Text ((Select File)				
S <u>D</u> E	(Select .sat Fil	e)			
Senta	aurus Visual - 3	Sentaurus <u>P</u> r	ocess l	_ink	
X <u>M</u> L	LogFile (Selec	st .xml File)			
<u>H</u> TMI	LL <mark>.</mark> gFile (Sel	ect .html File)		
Calib	ration Process	Files (SEdit)			
Calib	ration Profile F	iles (Inspect))		
Calib	ration Visual F	iles (SVisual)		
Run S	S <u>e</u> lected Visua	lizer Nodes	Togethe	er	
Comp	are Command	<u>F</u> iles of Sele	ected N	odes	
РСМ	Studio: Export	Current Sce	nario		
PCM	Studio: Config	ure Export			

Viewing Process Files

To view process files:

■ Choose the T button > Calibration Process Files (SEdit).

These files open in the SEdit text editor. For Sentaurus Process, the process files are the Sentaurus Process command files (b@node@_fps.cmd or pp@node@_fps.cmd) and general files (*.fps). The selection is restricted to the nr nodes of Sentaurus Process.

Figure 3 Specific viewers of files of Calibration Kit projects available from the visualization toolbar button

Viewing Profile Files

To view profile files:

■ Choose the The set of the set

The selected measured profiles (b@node@_*.plx) and simulated profiles (b@node@_*.plt) open in Inspect. All of the selected profiles are loaded into one xy plot. The selection is restricted to the nr nodes of Sentaurus Process.



Figure 4 An experiment visualized in Inspect

Viewing Visualization Files

To view visualization files:

■ Choose the The set of the set

The selected measured profiles (b@node@_*.plx) and the simulated profiles (b@node@_*.plt) open in Sentaurus Visual. All of the selected xy plot visualization scripts (n@node@_vis_out.tcl) are loaded and arranged next to each other. The selection is restricted to Sentaurus Visual nodes. For more information, see the *Sentaurus*TM *Visual User Guide*.

2: Working With Calibration Kit Projects Confidentiality Warning



Figure 5 Four experiments visualized in Sentaurus Visual

Confidentiality Warning

The file \$STROOT/tcad/\$STRELEASE/lib/fabpackagelib/confidentwarning.txt contains the text for the confidentiality warning that appears on the first page of the Project Wizard, Scenario Wizard, and Optimization Wizard. If the file is empty or does not exist, no confidentiality warning is displayed.

The file <code>\$STCALIB/confident.txt</code> contains the text for the confidentiality warning that appears in a separate dialog box when the third page of the Project Wizard and Optimization Wizard is displayed. If the file is empty or does not exist, no confidentiality warning is displayed.

CHAPTER 3 Calibration Library, Process Searches, and Profiles

This chapter provides details about the Calibration Library, process searches, and working with profiles.

Experiment Database: Calibration Library

This section describes the Calibration Library of the Calibration Kit.

Defining the Calibration Library

The default experiment database of the Calibration Kit – the Calibration Library – is defined using the system environment variable STCALIB. By default, STCALIB is set to the directory \$STROOT_LIB/fabpackagelib, which contains a database including process examples for demonstration purpose only and without any real experimental relevance.

The STCALIB databases (such as the Calibration Library or user databases) include three directories:

- The process directory, which is either processes_lig containing the process files in Ligament SPR syntax, or processes_sprocess containing the process files in Sentaurus Process syntax.
- The experiment directory experiments contains the SIMS profile files in xy plot format.
- The preference directory preferences contains the preference files (see Profiles on page 34).

Process File Syntax

In general, the Calibration Kit uses databases of process recipes in Ligament SPR syntax and Sentaurus Process syntax as input. However, the process recipes of the Calibration Library are delivered in Ligament SPR syntax and are translated to Sentaurus Process syntax before simulation. For the Calibration Library (as well as other user databases) to be input to the Calibration Kit, the general Ligament SPR syntax and Sentaurus Process syntax are subject to restrictions.

Restrictions on Ligament SPR Syntax

During the creation of a Calibration Kit project, the process recipes in Ligament SPR syntax are translated to Sentaurus Process syntax. First, the translator of the Calibration Kit uses the Ligament Translator. Then, some process flow translations specific to the Calibration Kit are applied (see Restrictions on Sentaurus Process Syntax).

In Ligament process flows, the arguments save, grid, debug, and checkld of the environment statement must all be set to false. The arguments title, region, and *_grid_* of the environment statement are irrelevant, since they are ignored during translation.

The 1D measurements are stated in an insert statement.

For Sentaurus Process, the 1D measurement statement is specified by the SetPltList statement, which is defined in calib_1d_*.fps. The SetPltList statement must only contain the species variable and a comment of the corresponding SIMS profile at the end of the same line (see Restrictions on Sentaurus Process Syntax).

For Sentaurus Process, the 1D profile load statement is specified by the profile statement, which must only contain the species variable and a comment of the corresponding profile at the end of the same line (see Restrictions on Sentaurus Process Syntax).

The process information <INFO> can be declared in a remark statement with processinfo '<INFO>' as text.

The measured sheet resistance value <VALUE> can be declared in a remark statement with sheetresistance 'Rs=<VALUE>' as text.

The measured cap-oxide thickness value <VALUE> in [nm] can be declared in a remark statement with OxideThickness <VALUE> as text.

Restrictions on Sentaurus Process Syntax

The process recipes in Sentaurus Process syntax in the database must include only process physics parameters. However, if you include simulator or model parameters in the process recipe files, the reliability of the simulation might be reduced.

The Sentaurus Process recipes must not contain line statements or region statements (the sourced file calib_1d_2017.09.fps or calib_KMC_2017.09.fps places these

statements in the input files of Sentaurus Process). During translation from Ligament SPR syntax to Sentaurus Process syntax, all statements preceding the first init statement are removed.

The 1D measurement statement is specified by the SetPltList statement, which is defined in calib_1d_2017.09.fps or calib_KMC_2017.09.fps. The SetPltList statement must contain only the species variable and a comment of the corresponding SIMS profile at the end of the same line, for example:

```
SetPltList BTotal ; # B_sims_profile.sims
```

The 1D profile load statement is specified by the profile statement, which must contain only the species variable and a comment of the corresponding profile at the end of the same line, for example:

```
profile name=Boron ; # B sims profile.sims
```

The process information <INFO> can be declared in a comment line with processinfo "<INFO>" as comment, for example:

```
## processinfo "B 0.5keV 1e15"
```

The measured sheet resistance value <VALUE> can be declared in a comment line with sheetresistance "Rs=<VALUE>" as a comment, for example:

sheetresistance "Rs=491"

The measured cap-oxide thickness value <VALUE> in [nm] can be declared in a comment line with OxideThickness <VALUE> as comment.

Process Searches

The module Quick Process Search (QPS) provides basic functionality for the process search in the process directory of the database. The Database Process Search (DBPS) module and the Calibration Project Process Search (CPPS) module are based on QPS.

Syntax of the QPS List File

The results of DBPS and CPPS as well as the input process list to the Calibration Kit project and the scenario wizards are QPS files file.qps. The file contains a header line and a process list.

3: Calibration Library, Process Searches, and Profiles Process Searches

The syntax is:

```
Processes Profiles Processinfo R_sheet
<process> <profile_1> <info> <r_sheet>
<profile_2>
```

Database Process Search

The Database Process Search (DBPS) looks for process flows written in the syntax of Ligament or Sentaurus Process in a directory (such as *STCALIB/processes_**). The processes that match the search criterion are listed in the process list file.

The search criterion – the process search pattern – consists of *conditions* connected by logical *operators* &&, ||, !, and grouped by parentheses. The operator && means *and*, || means *or*, and ! means *not*. The conditions consist of a *keyword* and *arguments*, for example, impl(element==As) or nimpl>0.

In general, the keyword takes only one argument. Only the impl() and diff() keywords can have more than one argument that are connected by logical operators. Some arguments consist of an argument type and a value connected by *comparators*: ==, <=, >=, <, >, or !=. Some arguments do not have comparators or argument types.

Table 1 lists the DBPS process flow keywords and their syntax, which are allowed in the DBPS criterion.

Keyword	Meaning	Argument	Example
impl()	Implantation statement scan, true if (1)	element, elem energy, en dose tilt rotation, rot	<pre>impl(elem==as) impl(en>0 && en<100) impl(dose>=1e12) impl(tilt!=0) impl(rot<1)</pre>
diff()	Diffusion statement scan, true if (1)	maxT (maximum temperature) totaltime peaktime (time at maximum temperature) pn2 (partial pressure for N_2) po2 (partial pressure for O_2) ph20 (partial pressure for H_2O)	<pre>diff(maxT==1000) diff(totaltime>5) diff(peaktime!=0) diff(pn2==1) diff(pn2>0 && po2<1) diff(ph20!=0)</pre>
plot()	Plot statement scan, true if (2)	X, Xtot, Xtotal, Xactive (where X is one of as, p, b, in, ge, sb, ga, al, n)	plot(bactive)
nimpl	Number of implantation statements scan, true if (3)	_	nimpl==1

Table 1 DBPS keywords and syntax

Keyword	Meaning	Argument	Example
ndiff	Number of diffusion statement scan, true if (3)	-	ndiff>0
file()	File name scan, true if (2)	<string></string>	file(USJ)
grep()	Process file scan, true if (2)	<string></string>	grep(comment)
(1) At least one statement exists in the process file, for which the arguments are evaluated as true.(2) At least one statement exists in the process file, for which the argument is evaluated as true.(3) Comparison is evaluated as true.			

Table 1 DBPS keywords and syntax

Calibration Project Process Search

The Calibration Project Process Search (CPPS) looks for experiments in a calibration project of Sentaurus Workbench. The tool scans process flows written in the syntax of Sentaurus Process in the same way as DBPS. However, CPPS scans variables of the Sentaurus Workbench. The experiments that match the search criterion are listed in the process list file.

The search criterion – the process search pattern – consists of *conditions* connected by logical *operators* &&, ||, !, and grouped by parentheses. The operator && means *and*, || means *or*, and ! means *not*. The conditions consist of a *keyword* and *arguments*, for example, impl(element==As) or nimpl>0.

In general, the keyword takes only one argument. Only the impl() and diff() keywords can have more than one argument that are connected by logical operators. Some arguments consist of an argument type and a value connected by *comparators*: ==, <=, >=, <, >, or !=. Some arguments do not have comparators or argument types.

Table 2 lists the DBPS process flow keywords and their syntax, which are allowed in the CPPS criterion.

Keyword	Meaning	Argument	Example
impl()	Implantation statement scan,	element, elem	<pre>impl(elem==as)</pre>
	true if (1)	energy, en	impl(en>0 && en<100)
		dose	<pre>impl(dose>=1e12)</pre>
		tilt	<pre>impl(tilt!=0)</pre>
		rotation, rot	<pre>impl(rot<1)</pre>

Table 2 Keywords and syntax for CPPS of DBPS

Keyword	Meaning	Argument	Example	
diff()	Diffusion statement scan, true if (1)	maxT (maximum temperature) totaltime peaktime (time at maximum temperature) pn2 (partial pressure for N_2) po2 (partial pressure for O_2) ph20 (partial pressure for H_2O)	<pre>diff(maxT==1000) diff(totaltime>5) diff(peaktime!=0) diff(pn2==1) diff(pn2>0 && po2<1) diff(ph2o!=0)</pre>	
plot()	Plot statement scan, true if (2)	X, Xtot, Xtotal, Xactive (where X is one of as, p, b, in, ge, sb, ga, al, n)	plot(bactive)	
nimpl	Number of implantation statements scan, true if (3)	_	nimpl==1	
ndiff	Number of diffusion statement scan, true if (3)	_	ndiff>0	
grep()	Process file scan, true if (2)	<string></string>	grep(comment)	
(1) At leas(2) At leas	(1) At least one statement exists in the process file, for which the arguments are evaluated as true.(2) At least one statement exists in the process file, for which the argument is evaluated as true.			

Table 2 Keywords and syntax for CPPS of DBPS

(3) Comparison is evaluated as true.

Table 3 lists the Sentaurus Workbench variable keyword and its syntax, which is allowed in the search criterion.

Table 3	Keywords and syntax for CPPS of Sentaurus Workbanch variable
Table 5	Reywords and syntax for CFFS of Sentaulus workbench variable

Keyword	Meaning	Argument	Example
process()	Process variable scan, true if at least one statement exists in the process file, for which the arguments are evaluated as true	<string></string>	process(USJ)

Profiles

This section discusses different aspects of profiles.

Visualizing Profiles

The visualization limits of each profile can be set in the preference file. The depth [nm] is set by:

```
set vis_xmin [integer]
set vis_xmax [integer]
```

The concentration $[cm^{-3}]$ is set by:

set vis_ymin [integer]
set vis_ymax [integer]

These values are the lower and upper limits of the visualization to be shown. A limit is evaluated by the visualization tool if the corresponding limit is not present in the preference file.

Comparing Profile Curves

Inspect calculates the differences of the measured and computed profile curves, which can be viewed in the Inspect log file. Optionally, the noise of the profile curves can be filtered by spline-based curve-smoothing. The difference is processed as the variable cv_delta_@integer@ of Sentaurus Workbench for each profile pair.

The quality limits of each profile can be set in the preference file. The depth [nm] is set by:

```
set sims_xmin [integer]
set sims xmax [integer]
```

These values are the lower and upper limits of the profile curve comparison. The default limits are used as borders if the above limits are not defined. The default values are:

set sims_xmin 5
set sims_xmax 50

The minimal and maximal concentrations $[cm^{-3}]$ are set by:

```
set sims_ymin [double]
set sims_ymax [double]
```

Concentrations outside of this range are set to the corresponding border value of the profile curve comparison. The default limits are used as borders if the above limits are not defined. By default, sims_ymin is half the concentration of the smoothed experiment profile curve at the depth sims xmax, while the default for sims ymax is 1e23.

NOTE If several profile pairs are visualized in one plot, only the comparison borders of the last profile pair are shown.

3: Calibration Library, Process Searches, and Profiles Profiles

The profile curve comparison can be performed using different methodologies:

- Relative logarithmic square difference
- Relative linear square difference
- Arithmetic mean of relative error
- Quadratic mean of relative error

Relative Logarithmic Square Difference

The formula for the relative logarithmic square difference for the experiment profile curve fe and the simulated profile curve fs is:

$$\int_{xmin}^{xmax} \left(\log(fe(x)) - \log(fs(x))\right)^2 dx \tag{1}$$

where the borders of integration *xmin* and *xmax* are the lower and upper limits of the profile curve comparison, respectively. The relative logarithmic square difference is set per depth $[\mu m^{-1}]$.

Relative Linear Square Difference

The formula for the relative linear square difference for the experiment profile curve fe and the simulated profile curve fs is:

$$\int_{xmin}^{xmax} (fe(x) - fs(x))^2 dx$$
(2)

where the borders of integration *xmin* and *xmax* are the lower and upper limits of the profile curve comparison, respectively. The relative linear square difference is set per depth $[\mu m^{-1}]$.

Arithmetic Mean of Relative Error

The formula for the arithmetic mean of the relative error for the experiment profile curve fe and the simulated profile curve fs is:

$$\frac{\int_{xmin}^{xmax} P(x) \left| \frac{fe(x) - fs(x)}{fe(x)} \right| dx}{\int_{xmin}^{xmax} P(x) dx}$$
(3)

where the borders of integration *xmin* and *xmax* are the lower and upper limits of the profile curve comparison, respectively. For each measurement point, P(x) results in 1, or else in 0.

Quadratic Mean of Relative Error

The formula for the quadratic mean (or root-mean-square) of the relative error for the experiment profile curve fe and the simulated profile curve fs is:

$$\begin{bmatrix}
xmax \\
\int P(x) \left| \frac{fe(x) - fs(x)}{fe(x)} \right|^2 dx \\
\frac{xmin}{xmax} \\
\int P(x) dx
\end{bmatrix}$$
(4)

where the borders of integration *xmin* and *xmax* are the lower and upper limits of the profile curve comparison, respectively. For each measurement point, P(x) results in 1, or else in 0.

3: Calibration Library, Process Searches, and Profiles Profiles